**Preferred Device** 

# Programmable Unijunction Transistor

## **Programmable Unijunction Transistor Triggers**

Designed to enable the engineer to "program" unijunction characteristics such as  $R_{BB},\ \eta,\ I_V,$  and  $I_P$  by merely selecting two resistor values. Application includes thyristor–trigger, oscillator, pulse and timing circuits. These devices may also be used in special thyristor applications due to the availability of an anode gate. Supplied in an inexpensive TO–92 plastic package for high–volume requirements, this package is readily adaptable for use in automatic insertion equipment.

#### **Features**

- Programmable  $R_{BB}$ ,  $\eta$ ,  $I_V$  and  $I_P$
- Low On–State Voltage 1.5 V Maximum @ I<sub>F</sub> = 50 mA
- Low Gate to Anode Leakage Current 10 nA Maximum
- High Peak Output Voltage 11 V Typical
- Low Offset Voltage 0.35 V Typical ( $R_G = 10 \text{ k}\Omega$ )
- Pb-Free Packages are Available\*



## ON Semiconductor®

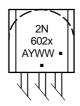
http://onsemi.com

## PUTs 40 VOLTS, 300 mW





#### **MARKING DIAGRAM**



2N602x = Device Code

x = 7 or 8

A = Assembly Location

Y = Year

WW = Work WeekPb-Free Package

(Note: Microdot may be in either location)

PIN ASSIGNMENT			
1	Anode		
2	Gate		
3	Cathode		

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## **MAXIMUM RATINGS** (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Power Dissipation* Derate Above 25°C	P <sub>F</sub> 1/θ <sub>JA</sub>	300 4.0	mW mW/°C
DC Forward Anode Current* Derate Above 25°C	I <sub>T</sub>	150 2.67	mA mA/°C
DC Gate Current*	I <sub>G</sub>	±50	mA
Repetitive Peak Forward Current 100 μs Pulse Width, 1% Duty Cycle 20 μs Pulse Width, 1% Duty Cycle*	I <sub>TRM</sub>	1.0 2.0	А
Non-Repetitive Peak Forward Current 10 μs Pulse Width	I <sub>TSM</sub>	5.0	А
Gate to Cathode Forward Voltage*	$V_{GKF}$	40	V
Gate to Cathode Reverse Voltage*	$V_{GKR}$	-5.0	V
Gate to Anode Reverse Voltage*	$V_{GAR}$	40	V
Anode to Cathode Voltage* (Note 1)	$V_{AK}$	±40	V
Capacitive Discharge Energy (Note 2)	E	250	μJ
Power Dissipation (Note 3)	$P_{D}$	300	mW
Operating Temperature	T <sub>OPR</sub>	-50 to +100	°C
Junction Temperature	T <sub>J</sub>	-50 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- \*Indicates JEDEC Registered Data
  1. Anode positive, R<sub>GA</sub> = 1000 Ω
   Anode negative, R<sub>GA</sub> = open
  2. E = 0.5 CV<sup>2</sup> capacitor discharge energy limiting resistor and repetition.
  3. Derate current and power above 25°C.

#### THERMAL CHARACTERISTICS

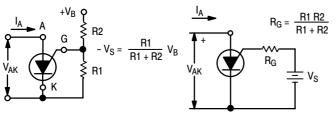
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	75	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{ heta JA}$	200	°C/W
Maximum Lead Temperature for Soldering Purposes (<1/16" from case, 10 seconds maximum)	T <sub>L</sub>	260	°C

## **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

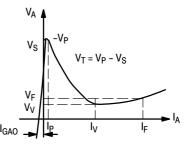
Characteristic		Fig. No.	Symbol	Min	Тур	Max	Unit
Peak Current* $(V_S = 10 \text{ Vdc}, R_G = 1 \text{ M}\Omega)$ $(V_S = 10 \text{ Vdc}, R_G = 10 \text{ k}\Omega)$	2N6027 2N6028 2N6027 2N6028	2,9,11	l <sub>P</sub>	- - - -	1.25 0.08 4.0 0.70	2.0 0.15 5.0 1.0	μΑ
Offset Voltage* $ (V_S = 10 \text{ Vdc}, R_G = 1 \text{ M}\Omega) $ $ (V_S = 10 \text{ Vdc}, R_G = 10 \text{ k}\Omega) $	2N6027 2N6028 (Both Types)	1	V <sub>T</sub>	0.2 0.2 0.2	0.70 0.50 0.35	1.6 0.6 0.6	V
Valley Current* $(V_S = 10 \text{ Vdc}, R_G = 1 \text{ M}\Omega)$ $(V_S = 10 \text{ Vdc}, R_G = 10 \text{ k}\Omega)$ $(V_S = 10 \text{ Vdc}, R_G = 200 \Omega)$	2N6027 2N6028 2N6027 2N6028 2N6027 2N6028	1,4,5	ΙV	- 70 25 1.5 1.0	18 18 150 150 –	50 25 - - -	μA mA
Gate to Anode Leakage Current* $(V_S = 40 \text{ Vdc}, T_A = 25^{\circ}\text{C}, \text{ Cathode Open})$ $(V_S = 40 \text{ Vdc}, T_A = 75^{\circ}\text{C}, \text{ Cathode Open})$		-	I <sub>GAO</sub>	-	1.0 3.0	10 -	nAdc
Gate to Cathode Leakage Current (V <sub>S</sub> = 40 Vdc, Anode to Cathode Shorted)		-	I <sub>GKS</sub>	-	5.0	50	nAdc
Forward Voltage* (I <sub>F</sub> = 50 mA Peak) (Note 4)		1,6	V <sub>F</sub>	-	0.8	1.5	V
Peak Output Voltage* $(V_G = 20 \text{ Vdc}, C_C = 0.2 \mu\text{F})$		3,7	V <sub>o</sub>	6.0	11	-	V
Pulse Voltage Rise Time ( $V_B = 20 \text{ Vdc}, C_C = 0.2 \mu\text{F}$ )		3	t <sub>r</sub>	-	40	80	ns

<sup>\*</sup>Indicates JEDEC Registered Data

<sup>4.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2%.



- 1A Programmable Unijunction with "Program" Resistors R1 and R2
- 1B Equivalent Test Circuit for Figure 1A used for electrical characteristics testing (also see Figure 2)



IC - Electrical Characteristics

Figure 1. Electrical Characterization

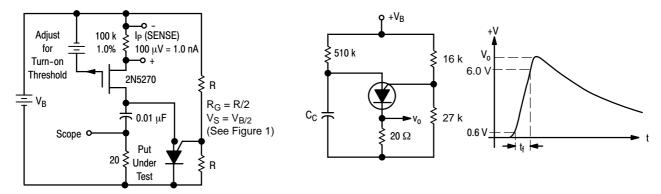


Figure 2. Peak Current (I<sub>P</sub>) Test Circuit

Figure 3. V<sub>o</sub> and t<sub>r</sub> Test Circuit

### **TYPICAL VALLEY CURRENT BEHAVIOR**

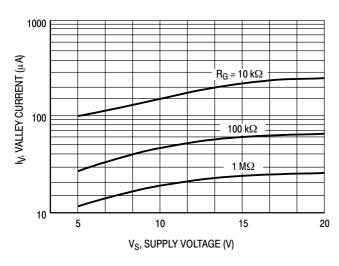
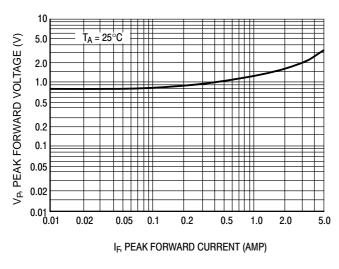


Figure 4. Effect of Supply Voltage

Figure 5. Effect of Temperature



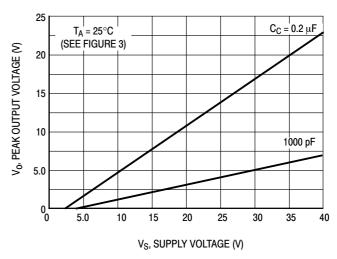
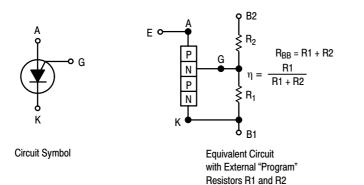


Figure 6. Forward Voltage

Figure 7. Peak Output Voltage



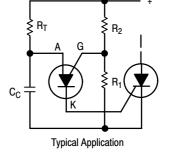


Figure 8. Programmable Unijunction

### **TYPICAL PEAK CURRENT BEHAVIOR**

### 2N6027

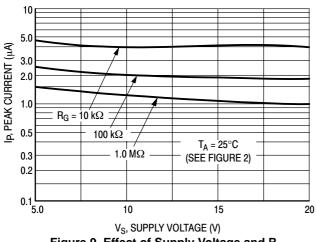


Figure 9. Effect of Supply Voltage and R<sub>G</sub>

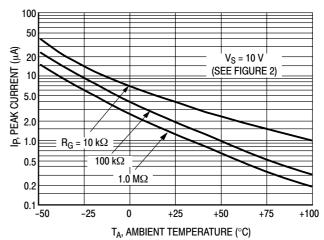


Figure 10. Effect of Temperature and R<sub>G</sub>

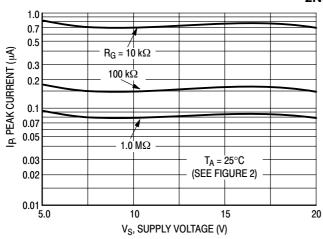


Figure 11. Effect of Supply Voltage and  $R_{\mbox{\scriptsize G}}$ 

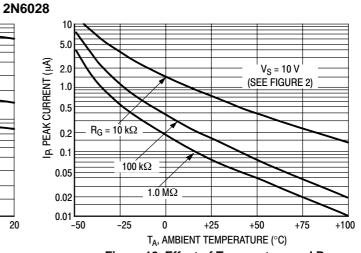


Figure 12. Effect of Temperature and R<sub>G</sub>

#### ORDERING INFORMATION

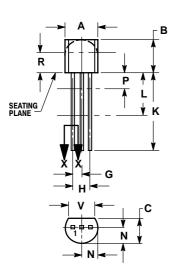
U.S.	European Equivalent	Shipping <sup>†</sup>	Description of TO-92 Tape Orientation	
2N6027				
2N6027G			N/A 5 II	
2N6028	5000 Units / Box	N/A – Bulk		
2N6028G				
2N6027RLRA				
2N6027RLRAG	2N6027RL1			
2N6028RLRA	2N6027RL1G 2000 / Tape & Reel	Round side of TO-92 and adhesive tape visible		
2N6028RLRAG				
2N6028RLRM				
2N6028RLRMG		2000 / Tana 8 America Day	Flat side of TO–92 and adhesive tape visible	
2N6028RLRP		2000 / Tape & Ammo Box	Boundaide of TO 00 and adhesive to a contribute	
2N6028RLRPG			Round side of TO-92 and adhesive tape visible	

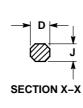
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>The "G" suffix indicates Pb-Free package available.

#### PACKAGE DIMENSIONS

TO-92 (TO-226AA) CASE 029-11 ISSUE AL





#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
  CONTOUR OF PACKAGE BEYOND DIMENSION R
- IS UNCONTROLLED.
  LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM

	INCHES		MILLIM	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

STYLE 16:

PIN 1 ANODE

GATE

2. CATHODE

ON Semiconductor and un are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice on semiconductor and are registered readerlands of semiconductor Components industries, Ltc (SCILLC). Solitude services the inject to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications. intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center

Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative